SG3525

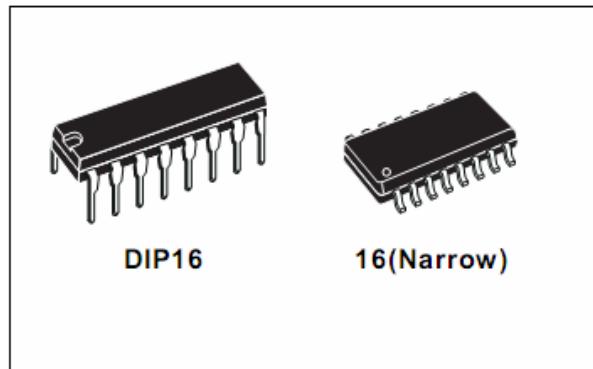## ● 特性

· 工作电压范围 8－35V；
· 5.0 准电压，精度±1％
· 振荡频率范围 100Hz－500KHz
· 振荡器同步信号输入端
· 死区时间可调
· 内置软启动电路
· 逐步脉冲关断
· 带滞回电压的输入欠压锁定
· PWM 锁定功能，禁止多脉冲

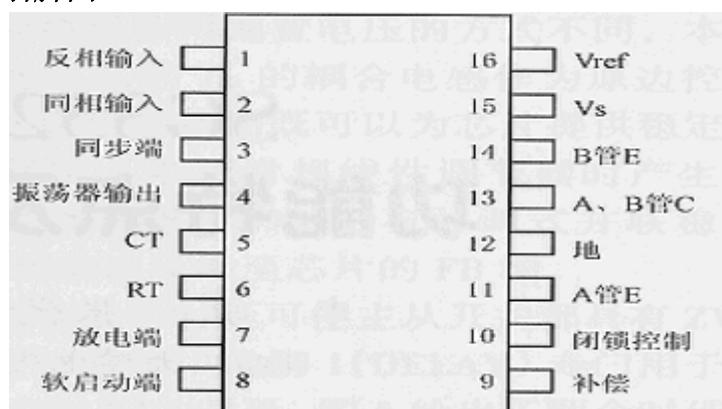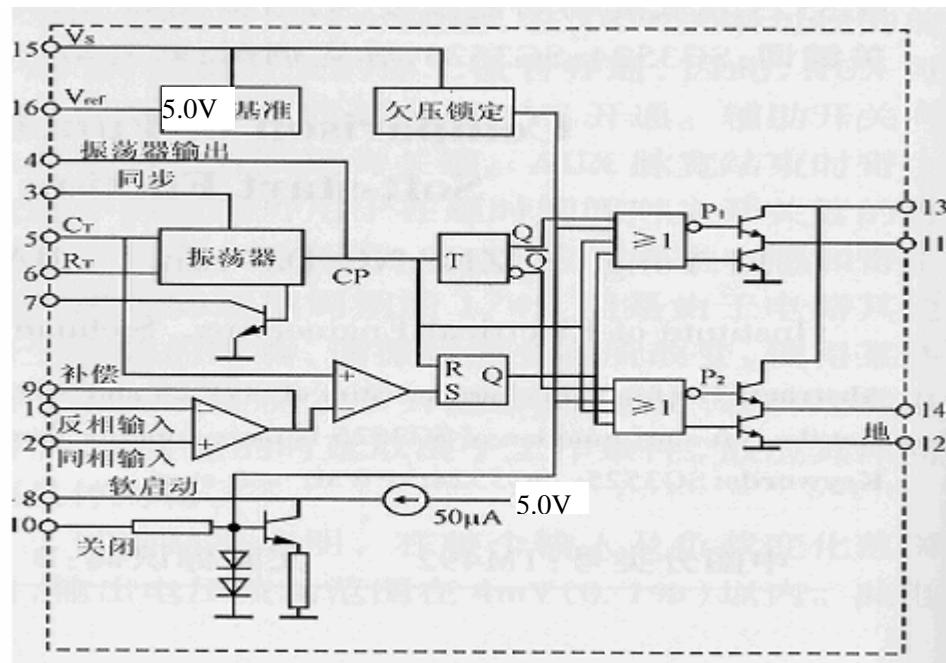## ● 封装图

DIP16   16(Narrow)

● 性能描述

SG3525 芯片＋5.0 准电压精度为±1％，由于基准电压值在误差放大器的输入共模范围内，因此无需外接电阻。SG3525 可以工作在主从模式、也可以与外部时钟同步。通过 C_T 与放电端之间的电阻可以调节死区时间。芯片内部的其它功能电路还包括：软启动电路、关断电路、欠压电路。

SG3525 控制芯片的输出级为大功率图腾柱式输出，其源电流和吸电流超过 200mA，其给出逻辑电平为"或非"逻辑，"断"状态时为低电平。

● 引脚图

引脚	编号	编号	引脚
反相输入	1	16	Vref
同相输入	2	15	Vs
同步端	3	14	B管E
振荡器输出	4	13	A、B管C
CT	5	12	地
RT	6	11	A管E
放电端	7	10	闭锁控制
软启动端	8	9	补偿

● 内部框图

● 极限工作参数

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	40	V
Collector Supply Voltage	V_C	40	V
Output Current, Sink or Source	I_O	500	mA
Reference Output Current	I_{REF}	50	mA
Oscillator Charging Current	$I_{CHG(OSC)}$	5	mA
Power Dissipation (T_A = 25°C)	P_D	1000	m/W
Operating Temperature	T_{OPR}	0 ~ +70	°C
Storage Temperature	T_{STG}	-65 ~ +150	°C
Lead Temperature (Soldering, 10 sec)	T_{LEAD}	+300	°C

● 参数（Vcc＝20V）

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
REFERENCE SECTION						
Reference Output Voltage	V_{REF}	$T_J = 25°C$	4.9	5.0	5.1	V
Line Regulation	ΔV_{REF}	V_{CC} = 8 to 35V	-	9	20	mV
Load Regulation	ΔV_{REF}	I_{REF} = 0 to 20mA	-	20	50	mV
Short Circuit Output Current	I_{SC}	V_{REF} = 0, $T_J = 25°C$	-	80	100	mA
Total Output Variation (Note 1)	ΔV_{REF}	Line, Load and Temperature	4.95	-	5.25	V
Temperature Stability (Note 1)	ST_T	-	-	20	50	mV
Long Term Stability (Note 1)	ST	$T_J = 125°C$,1 KHRS	-	20	50	mV
OSCILLATOR SECTION						
Initial Accuracy (Note 1, 2)	ACCUR	$T_J = 25°C$	-	± 3	± 6	%
Frequency Change With Voltage	$\Delta f/\Delta V_{CC}$	V_{CC} = 8 to 35V (Note 1, 2)	-	± 0.8	± 2	%
Maximum Frequency	$f_{(MAX)}$	$R_T = 2K\Omega$, $C_T = 470pF$	400	430	-	KHz
Minimum Frequency	$f_{(MIN)}$	$R_T = 200K\Omega$, $C_T = 0.1uF$	-	60	120	Hz
Clock Amplitude (Note 1, 2)	$V_{(CLK)}$	-	3	4	-	V
Clock Width (Note 1, 2)	$t_{W(CLK)}$	$T_J = 25°C$	0.3	0.6	1	μs
Sync Threshold	$V_{TH(SYNC)}$	-	1.2	2	2.8	V
Sync Input Current	$I_{I(SYNC)}$	Sync = 3.5V	-	1.3	2.5	mA

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
ERROR AMPLIFIER SECTION (V_{CM} = 5.1V)						
Input Offset Voltage	V_{IO}	-	-	1.5	10	mV
Input Bias Current	I_{BIAS}	-	-	1	10	μA
Input Offset Current	I_{IO}	-	-	0.1	1	μA
Open Loop Voltage Gain	G_{VO}	$R_L \geq 10M\Omega$	60	80	-	dB
Common Mode Rejection Ratio	CMRR	V_{CM} = 1.5 to 5.2V	60	90	-	dB
Power Supply Rejection Ratio	PSRR	V_{CC} = 8 to 3.5V	50	60	-	dB
PWM COMPARATOR SECTION						
Minimum Duty Cycle	$D_{(MIN)}$	-	-	-	0	%
Maximum Duty Cycle	$D_{(MAX)}$	-	45	49	-	%
Input Threshold Voltage (Note 2)	V_{TH1}	Zero Duty Cycle	0.7	0.9	-	V
Input Threshold Voltage (Note 2)	V_{TH2}	Max Duty Cycle	-	3.2	3.6	V
SOFT-START SECTION						
Soft Start Current	I_{SOFT}	V_{SD} = 0V, V_{SS} = 0V	25	51	80	μA
Soft Start Low Level Voltage	V_{SL}	V_{SD} = 25V	-	0.3	0.7	V
Shutdown Threshold Voltage	$V_{TH(SD)}$	-	0.6	0.8	1	V
Shutdown Input Current	$I_{N(SD)}$	V_{SD} = 2.5V	-	0.3	1	mA
OUTPUT SECTION						
Low Output Voltage I	$V_{OL\,I}$	I_{SINK} = 20mA	-	0.1	0.4	V
Low Output Voltage II	$V_{OL\,II}$	I_{SINK} = 100mA	-	0.05	2	V
High Output Voltage I	$V_{CH\,I}$	I_{SOURCE} = 20mA	18	19	-	V
High Output Voltage II	$V_{CH\,II}$	I_{SOURCE} = 100mA	17	18	-	V
Under Voltage Lockout	V_{UV}	V_8 and V_9 = High	6	7	8	V
Collector Leakage Current	I_{LKG}	V_{CC} = 35V	-	80	200	μA
Rise Time (Note 1)	t_R	$C_L = 1uF$, $T_J = 25°C$	-	80	600	ns
Fall Time (Note 1)	t_F	$C_L = 1uF$, $T_J = 25°C$	-	70	300	ns
STANDBY CURRENT						
Supply Current	I_{CC}	V_{CC} = 35V	-	12	20	mA

● 测试线路